

ZXTN19020DG

20V NPN HIGH GAIN TRANSISTOR IN SOT223

## Features

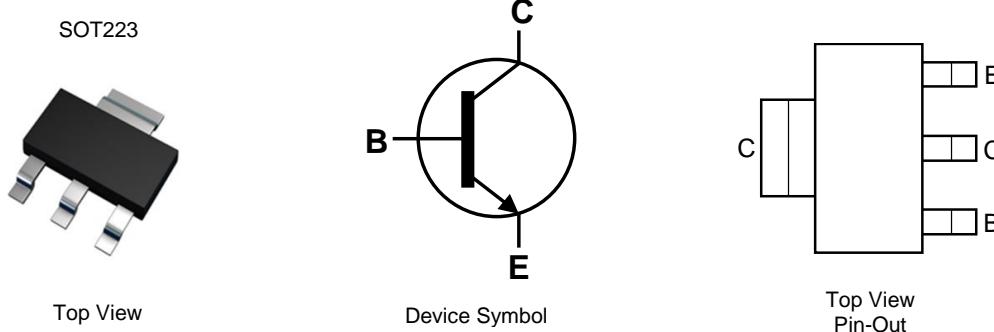
- $BV_{CEX} > 70V$
- $BV_{CEO} > 20V$
- $BV_{ECO} > 4.5V$
- $I_C = 9A$  High Continuous Current
- Low Saturation Voltage  $V_{CE(sat)} < 35mV$  @ 1A
- $R_{CE(sat)} = 20m\Omega$
- Complementary PNP Type: ZXTP19020DG
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- Qualified to AEC-Q101 Standards for High Reliability

## Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.112 grams (Approximate)

## Applications

- PSU Start-Up Circuit
- DC-DC Converters
- Motor Drive
- Relay, Lamp and Solenoid Drive



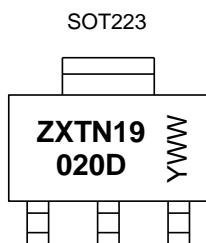
## Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN19020DGT	AEC-Q101	ZXTN19020D	7	12	1,000

Notes:

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

## Marking Information



ZXTN19020D = Product Type Marking Code  
YWW = Date Code Marking  
Y or  $\bar{Y}$  = Last Digit of Year (ex: 5= 2015)  
WW or  $\bar{WW}$  = Week Code (01~53)

**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	70	V
Collector-Emitter Voltage (forward blocking)	V <sub>CEx</sub>	70	V
Collector-Emitter Voltage	V <sub>Ceo</sub>	20	V
Emitter-Collector Voltage (reverse blocking)	V <sub>ECX</sub>	6	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	I <sub>C</sub>	9	A
Base Current	I <sub>B</sub>	1	A
Peak Pulse Current	I <sub>CM</sub>	20	A

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	P <sub>D</sub>	1.2	W mW/°C
		9.6	
		1.6	
		12.8	
		3	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	24	°C/W
		5.3	
		42	
		104	
Thermal Resistance, Junction to Lead	R <sub>θJL</sub>	78	°C/W
		42	
		23.5	
		16	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

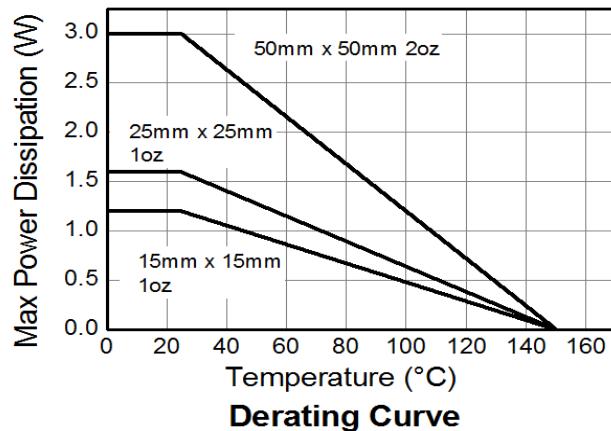
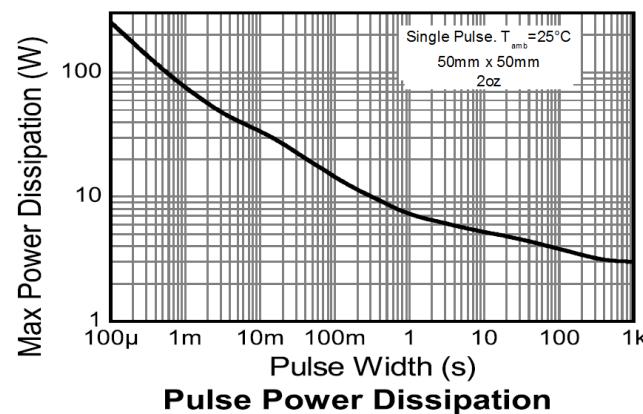
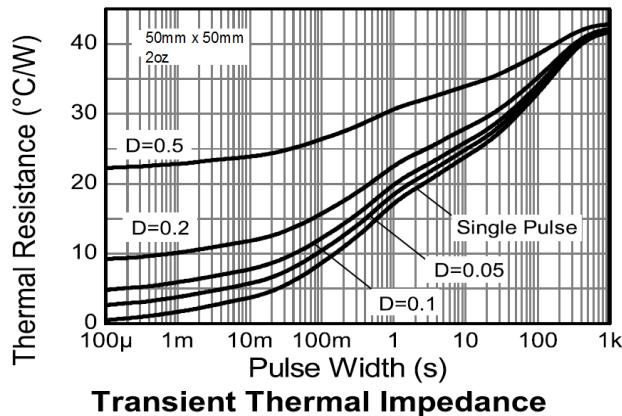
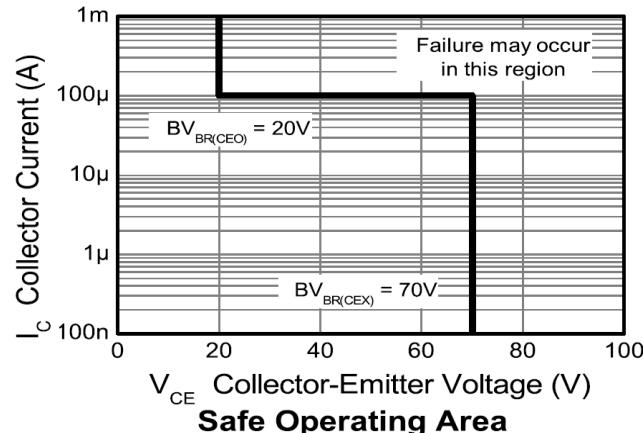
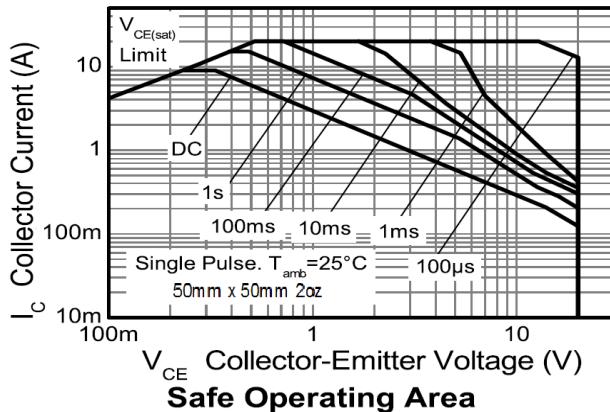
**ESD Ratings** (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:

- 5. For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
- 6. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.
- 7. Same as Note 6, except the device is mounted on 50mm x 50mm 2oz copper.
- 8. Same as Note 8 measured at t<5 seconds.
- 9. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

**Thermal Characteristics and Derating Information** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

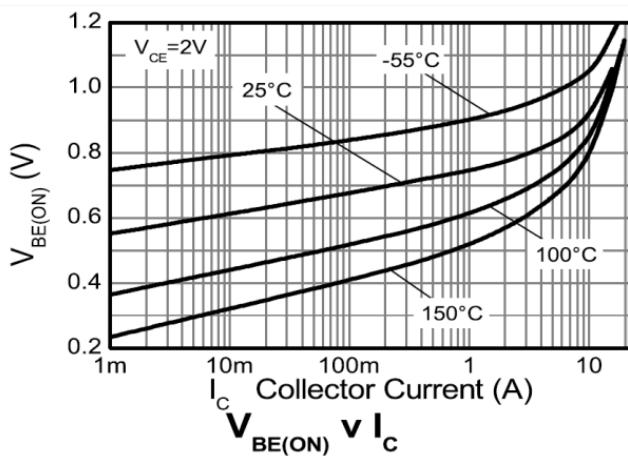
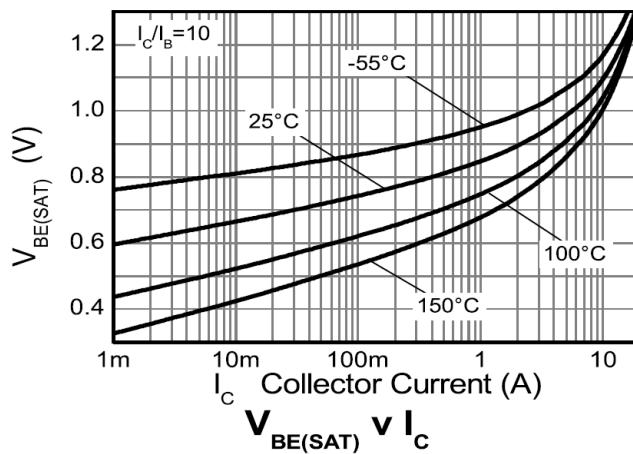
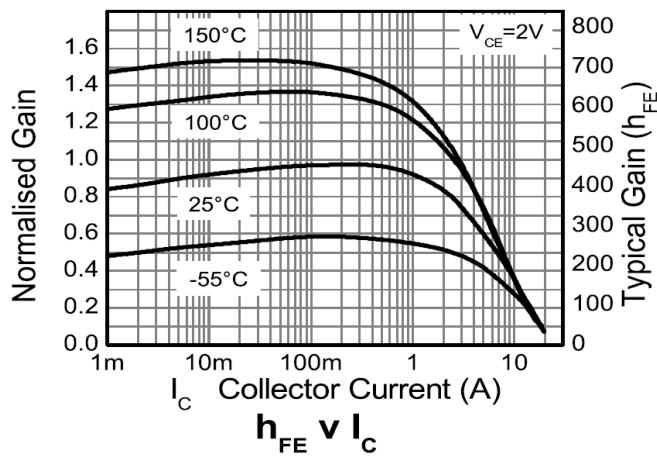
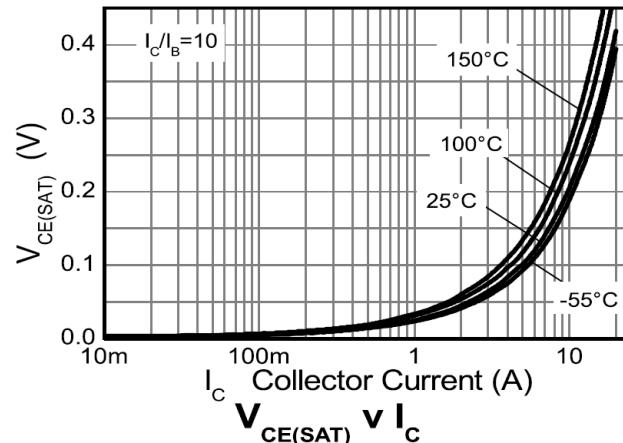
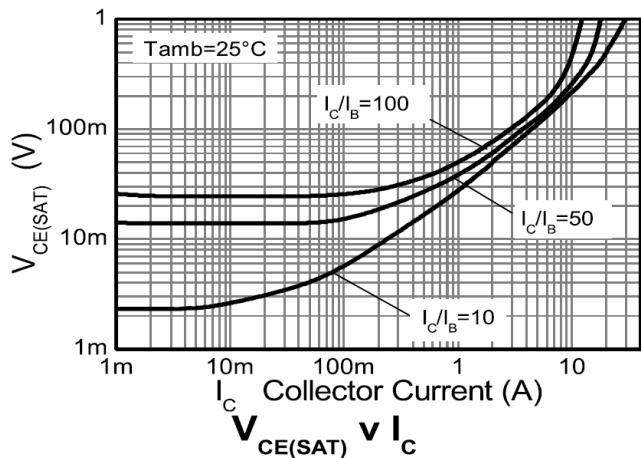


**Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$\text{BV}_{\text{CBO}}$	70	100	—	V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage (forward blocking)	$\text{BV}_{\text{CEX}}$	70	100	—	V	$I_C = 100\mu\text{A}, R_{BE} < 1\text{k}\Omega$ or $-1\text{V} < V_{BE} > 0.25\text{V}$
Collector-Emitter Breakdown Voltage (Note 11)	$\text{BV}_{\text{CEO}}$	20	30	—	V	$I_C = 10\text{mA}$
Emitter-Collector Breakdown Voltage (reverse blocking)	$\text{BV}_{\text{ECX}}$	6	8.4	—	V	$I_C = 100\mu\text{A}, R_{BC} < 1\text{k}\Omega$ or $0.25\text{V} < V_{BC} > -0.25\text{V}$
Emitter-Collector Breakdown Voltage (reverse blocking)	$\text{BV}_{\text{ECO}}$	4.5	5.7	—	V	$I_E = 100\mu\text{A}$
Emitter-Base Breakdown Voltage	$\text{BV}_{\text{EBO}}$	7	8.4	—	V	$I_E = 100\mu\text{A}$
Collector Cut-Off Current	$I_{\text{CBO}}$	—	< 1	50	nA	$V_{CB} = 70\text{V}$
		—	—	0.5	$\mu\text{A}$	$V_{CB} = 70\text{V}, T_A = +100^\circ\text{C}$
Collector-Emitter Cut-Off Current	$I_{\text{CEX}}$	—	—	100	nA	$V_{CE} = 70\text{V}, R_{BE} < 1\text{k}\Omega$ or $-1\text{V} < V_{BE} > 0.25\text{V}$
Emitter Cut-Off Current	$I_{\text{EBO}}$	—	< 1	50	nA	$V_{EB} = 5.6\text{V}$
Collector-Emitter Saturation Voltage (Note 11)	$V_{\text{CE}(\text{sat})}$	—	27	35	mV	$I_C = 1\text{A}, I_B = 100\text{mA}$
		—	50	70	mV	$I_C = 1\text{A}, I_B = 10\text{mA}$
		—	80	100	mV	$I_C = 2\text{A}, I_B = 20\text{mA}$
		—	63	80	mV	$I_C = 2\text{A}, I_B = 40\text{mA}$
		—	85	110	mV	$I_C = 4\text{A}, I_B = 400\text{mA}$
		—	200	250	mV	$I_C = 9\text{A}, I_B = 450\text{mA}$
Base-Emitter Saturation Voltage (Note 11)	$V_{\text{BE}(\text{sat})}$	—	1040	1150	mV	$I_C = 9\text{A}, I_B = 450\text{mA}$
Base-Emitter Turn-On Voltage (Note 11)	$V_{\text{BE}(\text{on})}$	—	910	1050	mV	$I_C = 9\text{A}, V_{CE} = 2\text{V}$
DC Current Gain (Note 11)	$h_{\text{FE}}$	300	450	900	—	$I_C = 100\text{mA}, V_{CE} = 2\text{V}$
		260	390	—	—	$I_C = 2\text{A}, V_{CE} = 2\text{V}$
		130	175	—	—	$I_C = 9\text{A}, V_{CE} = 2\text{V}$
		50	75	—	—	$I_C = 15\text{A}, V_{CE} = 2\text{V}$
		—	30	—	—	$I_C = 20\text{A}, V_{CE} = 2\text{V}$
Current Gain-Bandwidth Product (Note 11)	$f_T$	—	160	—	MHz	$V_{CE} = 10\text{V}, I_C = 50\text{mA}, f = 100\text{MHz}$
Input Capacitance (Note 11)	$C_{\text{ib0}}$	—	297	400	pF	$V_{EB} = 0.5\text{V}, f = 1\text{MHz}$
Output Capacitance (Note 11)	$C_{\text{ob0}}$	—	32.6	40	pF	$V_{CB} = 10\text{V}, f = 1\text{MHz}$
Delay Time	$t_d$	—	129	—	ns	$I_C = 1\text{A}, V_{CC} = 10\text{V}, I_{B1} = -I_{B2} = 10\text{mA}$
Rise Time	$t_r$	—	96	—	ns	
Storage Time	$t_s$	—	398	—	ns	
Fall Time	$t_f$	—	90	—	ns	

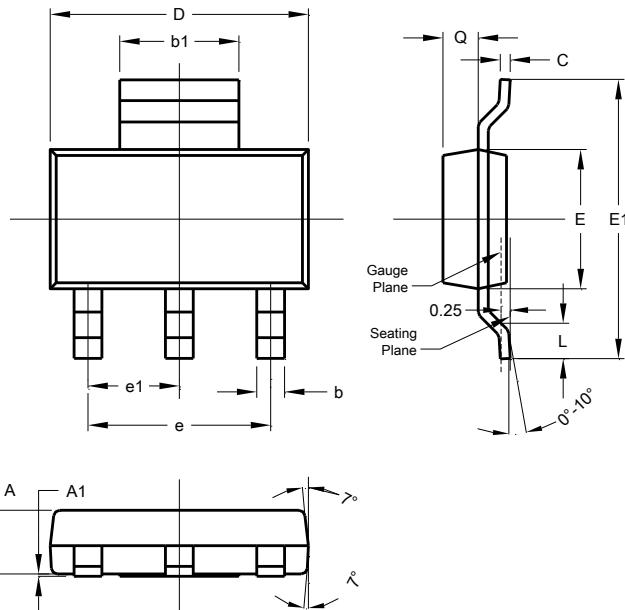
Note: 11. Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ . Duty cycle  $\leq 2\%$ .

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



## Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

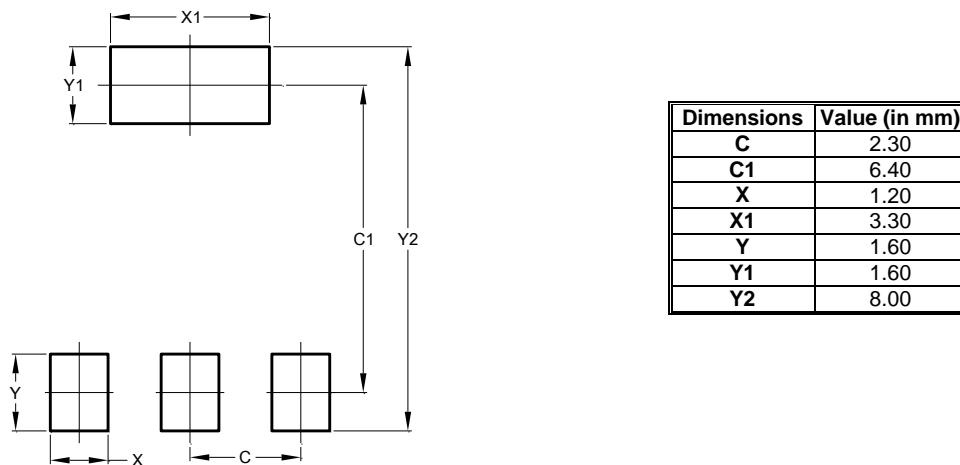


SOT223			
Dim	Min	Max	Typ
<b>A</b>	1.55	1.65	1.60
<b>A1</b>	0.010	0.15	0.05
<b>b</b>	0.60	0.80	0.70
<b>b1</b>	2.90	3.10	3.00
<b>C</b>	0.20	0.30	0.25
<b>D</b>	6.45	6.55	6.50
<b>E</b>	3.45	3.55	3.50
<b>E1</b>	6.90	7.10	7.00
<b>e</b>	-	-	4.60
<b>e1</b>	-	-	2.30
<b>L</b>	0.85	1.05	0.95
<b>Q</b>	0.84	0.94	0.89

All Dimensions in mm

## Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



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